SHERICY, L.F.

Storage of power cables. Energetik 13 no. 12:23-24 D '65 (MIRA 19:1)

1. Clavnyy inzhener kabel'noy seti Moskovskogo rayonnogo upravleniya energeticheskogo khozyaystva.

SMIRNOV, L. S.

Smirnov, L. S. -- "Process of Knitting Hosiery with a Covered Point, Eliminating Looping." Cand Tech Sci, Moscow Textile Inst, 4 Feb 54.

(Vechernyaya Moskva, 25 Jan 1954)

SO: Sum 168, 22 July 1954

MIRHOV, L.S., kandidat tekhnicheskikh nauk.

Knitting hosiery products with closed toe end without looping.

Leg. prom. 14 no.7:17-21 J1 '54. (MIRA 7:7)

(Hosiery)

SMIRBOV, L., kandidat tekhnicheskikh nauk; SOKOLOV, V.

Some data on the knit-geods industry in German Democratic Republic. Leg. prom. 16 no.1:54-55 Ja *56. (MERA 9:6) (Germany, East--Knit goods industry)

SMIRNOV, L.S., kand.tekhn.nauk

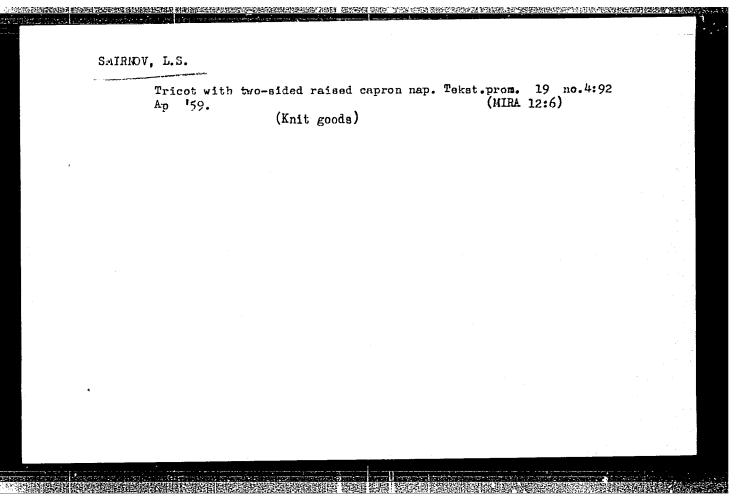
Specialization in Ukrainian S.S.R. knit-goods enterprises. Leg.
prom. 17 no.9:6-7 S '57. (MIRA 10:12)

(Ukraine-Knit goods industry)

SMIRNOV, L.S., kand. tekhn. nauk.

Improve the knitting of hosiory with closed tips. Ieg. prom. 18
no.5120-22 My '58.

(Hosiery)

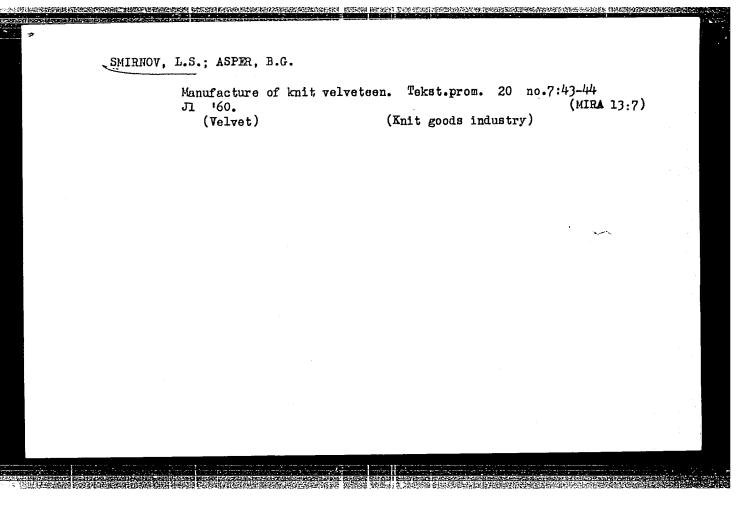


SMIRNOV, Leonid Stepenovich; LIPKOV, I.A., kand.tekhn.nauk, retsenzent;

DUKHOVNYY, F.N., red.; SHAPENKOVA, T.A., tekhn.red.

[Circular multiple-latch knitting machines] Kruglotrikotazhnye mnogozamochnye mashiny. Moskva, Izd-vo nauchno-tekhn.lit-ry RSFSR, 1960. 93 p. (MIRA 13:9)

(Knitting machines)



SMIRNOV, Leonid Stepanovich [Smyrnov, L.S.]; KERSEK, Vladimir Nikolayevich [Kersek, V.M.]; IYASHCHENKO, T.V., red.; SHVARTSSHTEYN, K.A., tekhn. red.

[New goods from synthetic fibers] Novi vyroby z khimichmyth volokon. Kyiv, Derzh. vyd-vo tekhn. lit-ry URSR, 1961. 17 p. (MIRA 15:3)

(Textile fibers, Synthetic)

SMIRNOV, L.S., kand. tekhn. nauk; STAROVOYTENKO, G.P., otv. red.; TUBOLEVA, M.V., red.

[Artificial fur] Iskusstvennyi mekh. Kiev, 1961. 39 p. (Obshchestvo po rasprostraneniiu politicheskikh i nauchnykh znanii Ukrainskoi SSR. Ser.6, no.15)

(Fur, Artificial)

CALL PLACE CLASS SERVICES CONTRACTOR CONTRACTOR AND A STREET OF THE SERVICE OF TH

SMIRNOV, Leonid Stepanovich; GONTARENKO, Aleksandr Nikolayevich;
GORDIYENKO, Mariya Georgiyevna; KRYLOV, Aleksandr Iosifovich;
NOVAK, Nikolay Stepanovich; LYASHCHENKO, T.V., red.; STARODUB,
T.A., tekhn. red.

[Manufacture of artificial fur] Proizvodstvo iskusstvennogo mekha. Kiev, Gos. izd-vo tekhn. lit-ry USSR, 1961. 138 p. (MIRA 15:4)

(Artificial fur)

SMIRNOV, L.S., kand.tekhn.nauk

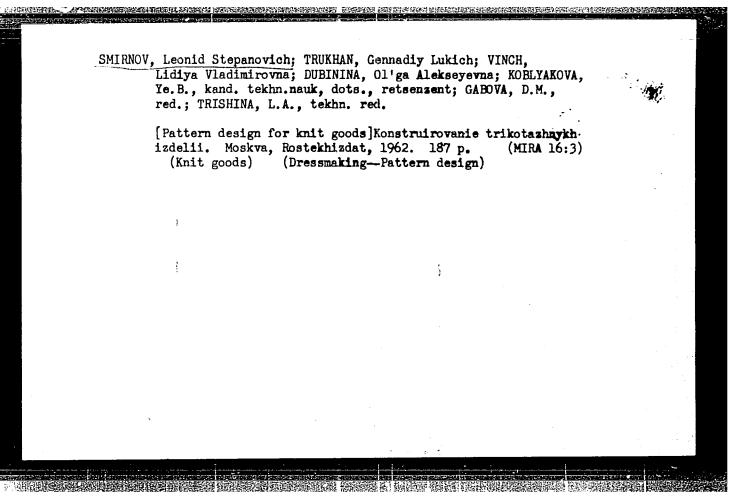
Bulky yarns and their use in the manufacture of knit goods.

Tekst.prom. 22 no.11:47-51 N '62. (MIRA 15:11)

1. Direktor Ukrainskogo nauchno-issledovatel'skogo instituta po pererabotke iskusstvennogo i sinteticheskogo volokna (UkrNIIPV).

(Yarn) (Knit goods)

APPROVED FOR RELEASE: 08/25/2000 CIA-RDP86-00513R001651520016-4"



SMIRMOV, L.S., kand. tekhn. nauk

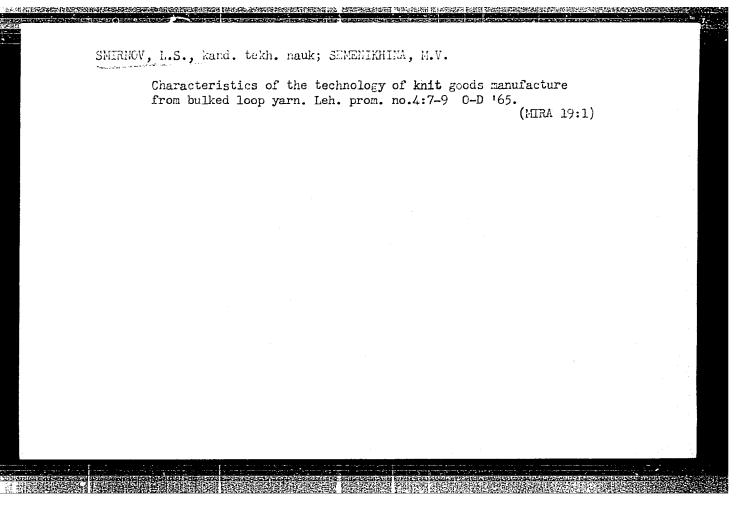
Manufacture of bulk yarns and knit goods in the U.S.A. Tekst. prom.
(SIRE 17:6)

1. Direktor Ukrainskogo nauchno-issledovatel'skogo institute co
pererabeleo isskusstvennykh i sintelicheskikh voloko.

PIGALEV, A.V.; SMIRNOV, L.P.; DZHALOVA, Ye, A.

Modification of the arrangement of cotton bales in front of the breaker unit in case of the increase of their number. Tekst.prom. 25 no.2:42-43 F 165. (MIRA 18:4)

1. Nachal'nik pryadil'nogo proizvodstva No.1 Khersonskogo khlopchatobumazhnogo kombinata (for Pigalev). 2. Nachal'nik sortirovochno-trepal'nogo tsekha pryadil'nogo proizvodstva No.1 Khersonskogo khlochatobumazhnogo kombinata (for Pigalev). 3. Starshiy inzh. laboratorii pryadil'nogo proizvodstva No.1 Khersonskogo khlochatobumazhnogo kombinata (for Dahalova).



SMIRNOV, L.S., kand.tekhn.nauk; KALECHITS, I.S.

Characteristics of the technology for the manufacture of men's socks from bulked loop yarn. Tekst.prom. 25 no.11:48-51 N 165. (MIRA 18:12)

1. Direktor Ukrainskogo nauchno-issledovatel skogo instituta po pererabotke iskusstvennykh i sinteticheskikh volokon (UkrNIIPV) (for Smirnov). 2. Zaveduyushchiy sektorom trikotazha laboratorii ob yemnykh nitey Ukrainskogo nauchno-issledovatel skogo instituta po pererabotke iskusstvennykh i sinteticheskikh volokon (for Kalechits).

APPROVED FOR RELEASE: 08/25/2000 CIA-RDP86-00513R001651520016-4"

L 44415-66 EWT(m)/EWP(j)/T RM

ACC NR: AP6021367 (A) SOURCE CODE: UR/0342/66/000/003/0071/0072

AUTHOR: Smirnov, L. S., (Director, Candidate of Technical Sciences); //
Polokhova, S. S., (Senior Research Associate)

ORG: Ukrainian Scientific Research Institute for the Processing of Artificial and Synthetic Fibers. [UkrNIIPV] (Nauchno-issledovatel' skiy institut po pererabotke iskusstevennykh i sinteticheskikh volokon)

TITLE: Some physicomechanical properties of bulked yarns

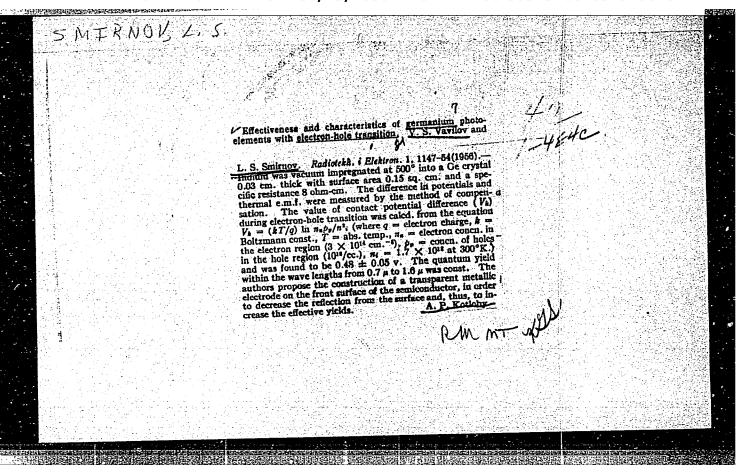
SOURCE: Tekstil' naya promyshlennost', no. 3, 1966, 71-72

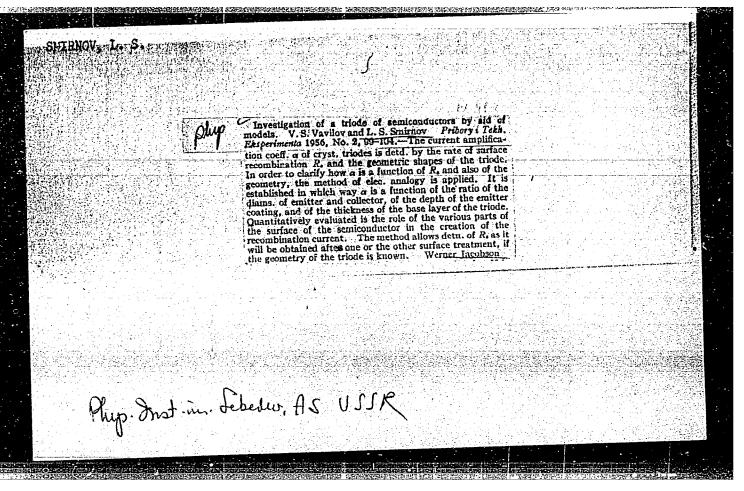
TOPIC TAGS: bulked yarn, chemical filament, banlon fiber, elastic fiber, meron fiber, fluflon fiber, agilon fiber, spun fiber chemical fiber, crimp

ABSTRACT: The article describes tests made to determine the amount of crimp and the elasticity of various types of bulked yarns, including fluffy, elastic, and meron yarns from the USSR and banlon, fluflon, agilon, and spun yarn from the USA. The amount of crimp was determined by a method developed at the Central Scientific Research Institute for Wool, (TsNIIShersti) mentioned in another work

Card 1/2

UDC: 677.494.001.4





SMIRNOV, L.S.

PA - 1377 CARD 1 / 3

WASILOW, W.S., SMIRHOW, L.S., GALKIN, G.H., SPIZYN, A.W., SUBJECT AUTHOR

The Formation of Defects on the Crystalline Lattice in Germanium TITLE

on the Occasion of a Bombardment by Fast Electrons. Zurn.techn.fis, 26, fasc. 9, 1865-1869 (1956)

reviewed: 10 / 1956 PERIODICAL Issued: 10 / 1956

The purpose of the present work was to clear up the dependence of the cross sections of formations of defects of the FRENKEL type on the electron energies W and to find out how many energetic levels, that are connected with the aforementioned structural defects of the crystal, influence conductivity, Experiments were carried out in the course of which the monocrystals of germanium with an electron conductivity were bombarded with monoenergetic electrons

 $(rac{ riangle y}{y}$ < 8%) of an energy of from 400 to 1000 keV. Electron irradiation and the

following measurements were carried out at room temperature. Thin (50 /4) monocrystalline plates were used. The energy loss in them amounted to not more than 60 keV. Three different methods were employed for measuring the specific resistance Q of the irradiated crystals: 1.) A homogeneous crystal with a known initial specific resistance Q was bombarded with electrons that impinged upon a surface of the greatest area. The resistance of the sample was measures, whereupon a layer having a thickness of 50 μ was ground together with the bombarded

PA - 1377 CARD 2 / 3 Žurn. techn.fis, <u>26</u>, fasc. 9, 1865-1869

surface and the resistance of the remaining part of the crystal was measured. From the distance between resistances the resistance of the part which was ground together was determined. . Herefrom its specific conductivity ϱ after

2.) A homogeneous crystal was bombarded as described under 1.) and then its bombardment was computed. bombarded surface was pasted on to a glass by means of Canada balsam where it was ground together to a thickness of 50 m. The resistance of the thin remaining

 $\bar{\mathfrak{Z}}_{\circ}$) The resistance of monocrystalline plates with a thickness of 50 μ , which were pasted on to glass, was measured, whereupon they were bombarded with elec-

trons. The resistance was then newly measured.

When measuring the resistance of thin crystals of germanium it is always necessary to reckor with the possibility of the formation of surface layers with increased resistance. The experiment showed that the threshold value of the energy W_{min} , from which onwards the conductivity of germanium crystals

diminishes by irradiation, is equal to 500 + 20 keV. The results obtained by the present work are not in contradiction to the hypothesis of JAMES and LARK -HOROVITZ if it is assumed that a donor level of the defect and an acceptor are near the corresponding zones. (The hypothesis says that to an atom in the

SMIRNOV, L.S.

"Energy of Ionization by Beta-Particles in Crystals of Germanium and Silicon," V.s. Vavilov, L.S. Smirnov, V.M. Patskevich, Moscow, USSR

Paper submitted for presentation at the International Conference on Radioisotopes in Scientific Research, Paris, 9-20 Sep 1957

Acad. Sci. USSR, Moscow

Presented at Conf. by V. S. Vavilov

SMIRNOV, L.S.

"The Structural Defects in Germanium Monocrystals Irradiated by Beta-Particles and Fast Neutrons and the Influence of These Defects on Electron-Hole Recombination," V.s. Vavilov, L.S. Smirnov, A.V. Spitsyn, V.M. Patskevich, M.v. Chukichev, Moscow, USŚR

Paper submitted for presentation at the International Conference on Radioisotopes in Scientific Research, Paris, 9-20 Sep 1957.

Acad. Sci. WSSR, Moscow

Presented at Conf. by V. S. Vavilov

SMIRNOV, LS

AUTHOR

VUL, B.M., VAVILOY, V.S., SMIRNOY, L.S., GALKIN, G.N., PATSKEVICH, V.M.,

89-5-7/24

TITLE

On the transformation of the energy of β -particles into electric energy in germanium crystals with P-N transitions. (O preobrazovanii energii β-chastits v electroenergiya * kristallakh germaniya s P-N-perekhodami. - Russian) Atomnaya Energiya 1957, Vol 2, Nr 6, pp 533-537 (USSR).

PERIODICAL

ABSTRACT

In 1955 the authors carried out experiments in the determination of the degree of efficiency of the transformation mentioned in the title. The P-N transitions were obtained by the melting of indium. Sr90 - Y90 preparations served as sources of β-particles. The total activity of the primary radicactive preparations amounted to 50,100, and 200 millicuries. As source of β-particles strontium sulphate tablets with 50 and 100 millicurie and strontium carbonate tablets with 200 millicurie were used. A diagram shows the β -spectra of these sources. Also measurements during irradiation of a semiconductor with artificially accelerated electrons (400 to 1150 keV) were carried out. The degree of efficiency

CARD 1/3

On the transformation of the energy of β -particles

into electric energy in germanium crystals with P-N transi-

the degree of efficiency of the transformer diminishes.

Further details are mentioned.

(With 8 Illustrations)

ASSOCIATION:

not given.

PRESENTED BY: SUBMITTED:

18.1. 1957.

AVAILABLE:

Library of Comgress.

CARD 3/3

PA - 2148

Probability of Charge Carriers by Frenkel Defekts in N-Germanium.

restitution of the original life. If the number of defects occuring in the chrystal lattice is compared with the attendant circumstance of reduction of life the capture cross-section of the carriers (holes) can be estimated (by the new-formed recombination-centers). The formula for the capture cross-section is derived on the assumption that the number of new recombination-centers is equal to the number of Frenkel-defects and that all these centers are filled with electrons. Experimental result for this domain which must be considered to be the lowest of the actual value, were approximatively 7.10-17cm². (1 image).

ASSOCIATION: Physical Institute "P.N.Lebedev", Moscow.

PRESENTED BY:

SUBMITTED:

1.10.1956

AVAILABLE:

Library of Congress.

Card 2/2

SMIRNOV, 15

AUTHOR:

Smirnov, L. S.

57-11-7/33

AND THE PROPERTY OF THE PROPER

TITLE:

Measurements of Small Lifetimes of Current Carriers in Germanium (Izmereniye: malykh vremen zhizni nositeley zaryada v germanii).

PERIODICAL:

Zhurnal Tekhn. Fiz., 1957, Vol. 27, Nr 11, pp. 2469-2471 (USSR).

ABSTRACT:

For the measurements types in form of small germanium plates with a pentransition on a great surface were used. Non-equilibrium carriers were excited by monochromatic light in vicinity of the semiconductor surface. The lifetime of the current carriers was computed according to the short circuit current and the number of the absorbed light quanta. Applied to germanium this method facilitates the measuring of a lifetime of from 2.10 to lo sec. This method is very practical for the detection of the temperature dependence of the lifetime and for the determination of the position of recombination levels. Formulae are derived by means of which the lifetime in the semiconductor layer can be determined experimentally by determination of the quantity. In the ratio of the number of carriers which take part in the short circuit current I to the number of carriers which take part in the short circuit current I to the number of carriers which develop by the light in the vicinity of the semiconductor surface within the time unit. The mentioned formulae effect

Card 1/2

USTR/Electricity - Semiconductors

G-3

Abs Jour

: Ref Zhur - Fizika, No 1, 1958, 1325

Vavilov, V.S., Spetsyn, A.V., Smirnov, L.S., Chukichev,

Author

: Physics Institute, Academy of Sciences, USSR, Moscow

Inst

Effect of Fast Neutron Irradiation on Recombination of

Title

Electrons and Holes in Germanium Crystals.

Orig Pub

: Zh. eksperim. i teor . fiziki, 1957, 32, No 4, 702-705

Abstract

On the basis on the transverse cross sections for the interaction of fast neutrons with germanium nuclei, using the Snyder and Neufeld method (Referat Zhur Fizika, 1956, No 7, 19840, No 12, 35072), the authors calculate the number of germanium atoms, shifted from their lattice points as a result of scattering of fast neutrons. It was established experimentally that the irradiation of germanium

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RDP86-00513R001651

S. Mirnov, L.S

经出现的特别外通日的经济的经济的经验的发展的发展的企业的发展的发展。2018年

PA - 2332

AUTHOR TITLE: VAVILOV, V.S., SMIRNOV, L.S., PATSKEVICH, V.M. Energy of Ionization by Electrons in Germanium crystals (Energyya ionisatsii elektronami v kristallakh germaniya, Russian).

Doklady Akademii Nauk SSSR, 1957, Vol 112, Nr 6, pp 1020 - 1022,

(U.S.S.R.)

Received: 4 / 1957

Reviewed: 5 / 1957

ABSTRACT:

PERIODICAL:

The authors carried out experiments on the determination of the average ionization energy in germanium on the occasion of excitation by electrons with 5 - 15 keV. For these experiments N-Type crystals with P - N - transitions, into which indium was melted, were used. Irradiation occurred on the side opposite to the indium electrode. The electronscompletely lost their energies within the domain of the N-type. The authors used the following denotations: N_1 - the number of carrier pairs actually created in the unit of time, N_1 - amperage of the electrons, N_2 - amperage of the holes. It holes that $B_1 = N_2/N_1 = I_2/I_1$, where I_1 corresponds to the primary current corresponding to the flux of the fast electrons. Up to very high intensities of the inciting bundle it further holds that $N_2 = \alpha N$. Due to recombination on the surface and in the interior of the crystal it always holds that $\alpha < 1$. For the multiplication factor B it holds that B = $N_0/N_1 = B_1/\alpha$ = I2/XI1. In the case of the crystals examined here did not depend on the wave length of the light. This holds good up to such wave

Card 1/3

CIA-RDP86-00513R001651520016-4" **APPROVED FOR RELEASE: 08/25/2000**

Energy of Ionization by Electrons in Germanium crystals. wave lengths in the case of which a considerable part of the light does not pass through the crystal but is absorbed in it. For the measuring of α the authors used light with $\lambda = 1,05 \,\mu$ which for the most is absorbed in layers with a maximum thickness of 1,0 μ . the crystals and changes on the occasion of the pumping out of the device and of bombardment with electrons. For the purpose of a continuous control of of in the course of measurements, the electrons were at the same time irradiated with electrons and light. The tests were carried out at pressures of 10-4 - 2.10-6 torr.No dependence of ξ (i.e. of the energy which must be used for the production of a carrier pair) on pressure (within the limits 2.10^{-6} - 10^{-4} torr) was noticed. The series of measurements on the crystals, which were subjected to different surface treatments, furnished the same value for \mathcal{E} . The mean value $\mathcal{E}=3.7\pm0.4$ eV was obtained from 4 series of measurements. In the case of V " 5 to 15 keV & does not change. This indicates slight energy losses of the primary electrons in the superficial oxide film which occurs on the occasion of the pickling of the germanium. The considerable similarity of the amounts of E on the occasion of ionization by electrons and α particles may apparently be ex-

Card 2/3

PA - 2332

Energy of Ionozation by Electrons in Germanium Crystals. plained by the fact that in the second case a considerable part of the charge carrier pairs occurs under the effect of relatively fast d-electrons. (1 illustration)

ASSOCIATION: Not given.

PRESENTED BY: Member of the Academy D.V.SKOBEL'TSYN.

SUBMITTED:

24.10.1956

Library of Congress. AVAILABLE:

Card 3/3

AUTHORS:

Vavilov, V. S., Smirnov, L. S., Spitsyn, A. V., 57-28-5-6/36

Patskevich, V. M., Galkin, G. N.

TITLE:

On Defects in a Crystal Lattice in n-Germanium (O defektakh

kristallicheskoy reshetki v germanii N-tipa)

PERIODICAL:

Zhurnal Tekhnicheskoy Fiziki, 1958, Vol. 28, Nr 5, pp. 960-

-961 (USSR)

ABSTRACT:

In the previous paper the authors communicated the investigation results of germanium crystals of the n- type subjected to an electron bombardment with energies ranging from 0,4 to 1 MeV (Ref 1). There, the experimentally determined modifications of the specific resistance with respect to the energy and the amount of fast electrons, was opposed to the theory of defect formation because of an electron dispersion by means of germanium nuclei by Frenkel'. V. V. Galavanov to whom the authors are indebted, indicated a num erical error. This error was committed in the computation of the integral cross-sections 2

of electron dispersion on a nucleus at all angles from π to the angle θ_{\min} at which the electron transfers the minimum energy to the nucleus necessary for the formation of a defect.

The newly computed theoretical values of corresponding to bmin

Card 1/2

On Defects in a Crystal Lattice in n-Germanium

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57-28-5-6/36

a threshold energy of 500 keV as well as the experimentally determined sections of center formation, which remove the electrons from the conduction zone are given in the table. From this follows, that the experimental values, which have been obtained in the mentioned paper and which were verified by subsequent experiments, do not correspond to the conception that at energies W varying from the threshold energy (W =0,5 MeV) to W = 0,96 MeV the constant defects in n-type germanium are produced according to the law $\sum_{i=1}^{N} f(w_i)$

It is intended to conduct in the near future experiments with n-type crystals with strongly differing Fermi levels and to determine, whether the difference between theory and experiment is dependent upon the low degree of filling of the capture centers. There are 1 table and 1 Soviet reference.

ASSOCIATION:

Fizicheskiy institut im. P. N. Lebedeva AN SSSR, Moskva(Physics:

Institute imeni P. N. Lebedev AS USSR, Moscow)

SUBMITTED:

January 18, 1958

Card 2/2

1. Germanium crystals--Analysis

67391 SOV/181-1-9-9/31 24.7700 Smirnov, L. S., Glazunov, P. A. 24(2), 21(8) The Spatial Distribution of Lattice Defects in Germanium AUTHORS: Crystals/Irradiated by Fast Electrons) Fizika tverdogo tela, 1959, Vol 1, Nr 9, pp 1376 - 1378 (USSR) TITLE: The aim of the work under review was to investigate the spatial distribution of the lattice defects due to electron PERIODICAL: irradiation by measuring the electrical conductivity in the ABSTRACT: direction of the electron beam incidence. Figure 1 shows a scheme of the experimental setup. The measurements of conductivity were made every 10 - 50 μ with a probe by the use of a PPTV potentiometer. The defect concentration was sufficiently small so that every change in conductivity was due to a change in the carrier concentration \triangle n or \triangle p. \triangle n is proportional to the defects produced. The An distribution in the sample interior must therefore correspond to the distribution of the structural defects, if the properties of the defects do not depend on the electron energy. Surface influences can be eliminated by a corresponding choice of the sample dimensions. The dimension selected for p- and n-Ge was Card 1/3

67391

The Spatial Distribution of Lattice Defects in Germanium SOV/181-1-9-9/31 Crystals Irradiated by Fast Electrons

assistance in measurements. There are 3 figures and 2 Soviet

references.

ASSOCIATION: Fizicheskiy institut AN SSSR im. P. N. Lebedeva Moskva

(Physics Institute of the AS USSR imeni P. N. Lebedev, Moscow)

SUBMITTED: March 7, 1959

Card 3/3

SMIRNOV, L.S.

5/181/60/002/007/041/042 B006/B060

24.6820 24.7500

AUTHOR:

Radiation Disturbances in Grystals

TITLE:

Fizika tverdogo tela, 1960, Vol. 2, No. 7, Pp. 1669-1670

TEXT: Irradiation with fast particles affects the physical properties the author discusses the of crystals considerably. In the present paper TEXT: Irradiation with fast particles affects the author discusses the author discusses of crystals considerably. In the present paper the to its bombardment of crystals considerably defects of a crystal due to its bombardment of crystals due to its bombardment. of crystals considerably. In the present paper the author discusses the type and formation of lattice defects of a crystal due to its bombardment at this singlest disturbances are brought about in this with fast electrons. The simplest vaporate from Experimental results that atoms evaporate of vacancies). Experimental results case. One may assume that nodes (formation of vacancies) to between the nodes of vacancies. case. One may assume that atoms evaporate from their sites and occupy a place between the nodes (formation of vacancies). Experimental results formation of vacancies and occupy a the nodes (formation of vacancies). Experimental results formation is the place between the nodes (formation concept. Another assumption is the place only in poor agreement with this concept. place between the nodes (formation of vacancies). Experimental results then assumption is the place between the nodes (formation of vacancies). Experimental results the assumption is the place between the nodes (formation of vacancies). Experimental results the assumption is the place between the nodes (formation of vacancies). Experimental results then assumption is the place between the nodes (formation of vacancies). Experimental results are assumption is then the nodes (formation of vacancies). Experimental results are assumption is then the nodes (formation of vacancies). Experimental results are assumption is the nodes (formation of vacancies). Experimental results are assumption is the nodes (formation of vacancies). Experimental results are assumption is the nodes (formation of vacancies). It is the experimental conditions are only in poor agreement which better fits the experimental conditions. It is the experimental conditions are only discussed. are only in poor agreement with this concept. Another assumption is then the experimental conditions. 10 ev, another assumption is a to ev, another assumption is a to ev, acquires an energy of some than a sumption with better fits the experimental conditions. 10 ev, acquires an energy more for thoroughly discussed, which better fits acquires an energy more used up thoroughly discussed, which a fast particle, acquires an energy will be immediate into its on constants, and almost its energy all, the immediate into its place, and this small region can pass over it will, in aconstants, and heating affects, small region can pass over few lattice constants, and this small region can pass of the atom considered, and this small region of the atom considered, and this small region can pass over neighbors of the atom considered, and this small region can pass over the string the lattice. PERIODICAL: heating the lattice. This heating affects, first of all, the immediate into neighbors of the atom considered, and this small region can pass over into neighbors of the atom considered.

card 1/3

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82556

Radiation Disturbances in Crystals

s/181/60/002/007/041/042 B006/B060

the molten state. Substances that expand on melting are exposed to local pressures of the order of 104 kg/cm². As a result of this pressure, atoms may be shifted in the excited region. Some crystals exhibit, when molten, a variation in the short-range order of their atoms, which, for example, leads in the case of silicon and germanium to a decrease in volume. The radiation defect thus consists of a disturbance of the order due both to pressure and variation in the short-range order. The author attempts to estimate the minimum energy necessary for the purpose. For germanium, the minimum is 380 kev, and if the energy required for breaking one atomic bond is assumed to be 0.6 ev, it is found, in a very rough estimation, that the smallest volume in which the order may be re-arranged is equal to the volume of 26 atoms. Similar conditions are found for silicon. If the ideas discussed here are correct the limiting energy is shifted depending on the temperature at which irradiation takes place. If one irradiation is carried out at room temperature and another at 200°C higher, the limit energy of germanium can be shifted by 20 - 30 key. The author finally thanks V. S. Vavilov for his discussion.

33096 s/638/61/001/000/019/056 B104/B138

24.7700 (1043,1164,1385)

Smirnov, L. S., Glazunov, P. Ya.

Volume distribution of lattice defects in germanium crystals AUTHORS:

irradiated with fast electrons TITLE:

Tashkentskaya konferentsiya po mirnomy ispol rovaniya atomnoy energii. Tashkent, 1959. Trudy. v. 1. Tashkent, 1961, SOURCE

TEXT: The determination of defect concentrations in Ge crystals was based on the relation between the defect concentration and the concentration of additional acceptor centers. The variation in the conductivity of irradiated crystals was studied by taking the potential distribution (Fig. 1) with a probe at intervals of 10 - 50 p. . The defect concentration was so low that it did not affect mobility and the entire variation in conductivity was due to variation in carrier concentrations. The n- and p-type germanium samples had dimensions of 1.0°3.0°5.0 mm, and β_0 =

10 - 15 ohm.cm and 40 - 50 ohm.cm, respectively. The samples were irradia-Card 1/32

APPROVED FOR RELEASE: 08/25/2000

CIA-RDP86-00513R001651520016-4

5/181/61/003/011/001/056 B102/B138

26.2421

Plotnikov, A. F., Vavilov, V. S., and Smirnov, L. S. Kinetics of photoconductivity in p-type neutron-irradiated

AUTHORS:

Fizika tverdogo tela, v. 3, no. 11, 1961, 3253 - 3259 TITLE:

TEXT: The defect formation due to fast-neutron irradiation was investi-That: The delect formation due to last-neutron irradiation was investigated in single crystals of p-type silicon. (pmm. 3. 8. 1961). The described by the authors in an earlier paper (pmm. 3. 8. 1961). gated in single crystals of p-type silicon. The specimens used nad by the authors in an earlier paper (FTT, 3, 8, 1961). The described by the authors in an earlier paper irradiation in the defect level avatem arising due to the fast-neutron irradiation. described by the authors in an earlier paper (FTT, 2, 8, 1961). The in the defect level system arising due to the fast-neutron irradiation in at defect level system arising due to the photoconductivity investigated forbidden band is shown in Fig. 1. The photoconductivity investigated forbidden band is shown in Fig. 1. The photoconductivity investigated forbidden band is shown in Fig. 1. PERIODICAL: forbidden band is shown in Fig. 1. The photoconductivity investigated ev, was that connected with the electron transitions to the levels $E_v^{+0.30}$ ev, E_{v} + 0.38 ev and E_{v} + 0.45 ev. Temperature was around 100°K. The electron was excited by steep-sided light pulses with rise and decay times of tron was excited by steep-sided light pulses with rise and decay times of vion was excited by steep-sided light pulses with rise and decay times of 5 usec each. Photoconduction relaxation was studied separately for each 1 percentage of the property 5 μsec each. Photoconduction relaxation was studied separately for each level by two independent methods. E_V + 0.30 eV: (1) The build-up of shotoconductivity was found at Anoma on an 3HO-1(ENO-1) oscillations. level by two independent methods. Ev + U. 70 ev: (1) HE Dullin-up of photoconductivity was found at $\Delta p \sim p_0$ on an 3HO-1(ENO-1) oscilloscope.

APPROVED FOR RELEASE: 08/25/2000

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30769 \$/181/61/003/011/001/056 B102/B138

Kinetics of photoconductivity in ...

 $m_{_{\scriptsize O}}$, the initial electron concentration at level M, was found to be and $\sigma_p \approx 3 \cdot 10^{-14} \text{cm}^2$ was determined for the hole trapping cross section. (2) The build-up curves $\Delta p_{bn} = f(t)$ were investigated for p_o≯ △p. It was confirmed that the building is governed by an exponential law. The parameters of the centers were found to be $m_0 \approx 10^{13} \text{ cm}^{-3}$, $\sigma_p \approx 3 \cdot 10^{-14} \text{cm}^2$ (first illumination) and $m \approx 10^{13} \text{cm}^{-3}$, $\sigma_p \approx 2.5 \cdot 10^{-14} \text{cm}^2$ (second illumination). $E_v + 0.38 \text{ ev}$: (1) Recording of the relaxation pulses without constant illumination for $p_0 \approx 8 \cdot 10^3 \, \mathrm{cm}^{-3}$ and $\Delta p \approx 3 \cdot 10^8 \, \mathrm{cm}^{-3}$ yielded: $m_0 q I \sim 10^9 \, \mathrm{cm}^{-3} \cdot \mathrm{sec}^{-1}$ and $\sigma_p \approx 5 \cdot 10^{-17} \, \mathrm{cm}^2$. (2) Recording of Δp_{m} with constant illumination ($p_0 \approx 6 \cdot 10^9 \, \mathrm{cm}^{-3}$ and $\Delta p \approx 3 \cdot 10^8 \, \mathrm{cm}^{-3}$) yielded: $m_0 q I \sim 10^9 \, \mathrm{cm}^{-3} \cdot \mathrm{sec}^{-1}$ and $\sigma_p \approx 7 \cdot 10^{-17} \, \mathrm{cm}^2$. (q - capture cross section of a photon by an electron at the lambda I_{m} and I_{m} are selectron at the I_{m} and I_{m} and I_{m} and I_{m} are selectron at the I_{m} and I_{m} and I_{m} and I_{m} and I_{m} are I_{m} and I_{m} and I_{m} and I_{m} and I_{m} are I_{m} and I_{m} and I_{m} and I_{m} are I_{m} and I_{m} and I_{m} and I_{m} are I_{m} and $I_{$ of a photon by an electron at the level M; I - intensity of exciting light.) $E_v + 0.45$ ev: Δp_{bn} was studied as a function of time. It was found that for t < 0.2 sec carriers localized at centers with E_v+ 0.30 ev \times Card 2/4

Kinetics of	photoconductivity in	30769 S/181/61/003/011/001/056 B102/B138		
for remarks, 4 Soviet and	critics and help. There are 1 1 non-Soviet.	O figures and 5 references:		
ASSOCIATION:	Fizicheskiy institut im. P. N (Physics Institute imeni P. N	. Lebedeva AN SSSR Moskva . Lebedev AS USSR, Moscow)		
SUBMITTED:	April 29, 1961			
Fig. 1	Ec.016			
	$\underline{E_{y}+0.30}$ $\underline{E_{y}+0.35}$ $\underline{E_{y}+0.35}$ $\underline{E_{y}+0.35}$			
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5/181/62/004/009/044/045 B104/B186

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Smirnov, L. S., Vavilov, V. S., and Gerasimenko, N. N.

AUTHORS:

Kinetics of silicon recombination radiation

TITLE:

Fizika tverdogo tela, v. 4, no. 9, 1962, 2628-2629

PERIODICAL:

TEXT: The possibility of studying the kinetics of silicon recombination radiation is examined. Rectangular current pulses were fed into Si crystals with p-n junctions. The recombination radiation from the crystal was taken by a photomultiplier, amplified with a broad-band amplifier and observed with an oscilloscope. The crystals had been produced by diffusion of phosphorus and by fusing aluminum on to the surface. The injection coefficient was assumed to remain constant up to current densities of 10 a/cm². Results: The attenuation of recombination luminescence can be well described by an exponential law. The time constants of attenuation are approximately 2.7 microseconds for crystals with diffused junctions, 1.5 microseconds for crystals with fused junctions. When the crystal is cooled to liquid nitrogen temperature the pulse amplitude does not decrease in proportion to the change in the

Card 1/2

APPROVED FOR RELEASE: 08/25/2000

CIA-RDP86-00513R001651520016-4"

The theory of radiation defect ...

S/181/62/004/012/016/052 B104/B102

$$\frac{N_A}{N_{A0}} = \frac{1}{\left(\frac{N_{A0}}{M} \frac{v_e^{-U/kT}}{\sigma_{s.}} \sigma_{p.}\right)t + 1}.$$

(7),

can be written in the form f = 1/(At+1). If A is chosen suitably, curves obtained from (7) agree fairly well with experimental data obtained by W. L. Brown and W. M. Angustyniak (J. Appl. Phys., 30, 1258, 1959) and by G. Bemsky and W. M. Angustyniak (Phys. Rev., 108, 645, 1957). There are 3 figures.

ASSOCIATION: Fizicheskiy institut im. P. N. Lebedeva AN SSSR Moskva

(Physics Institute imeni P. N. Lebedev AS USSR, Moscow)

SUBMITTED: July 6, 1962

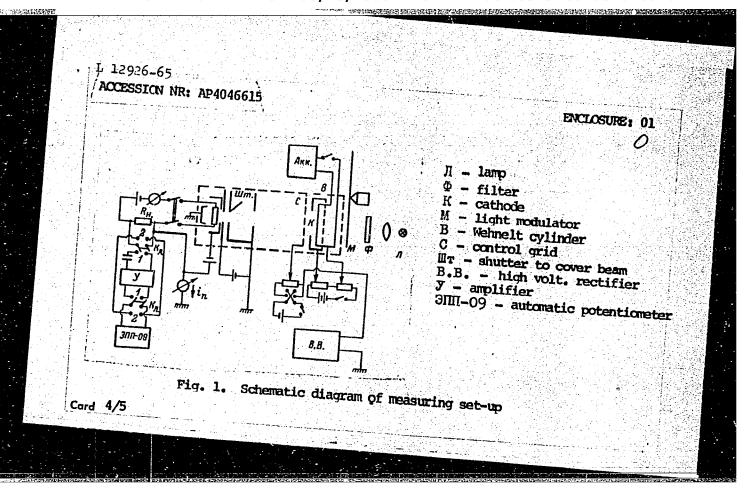
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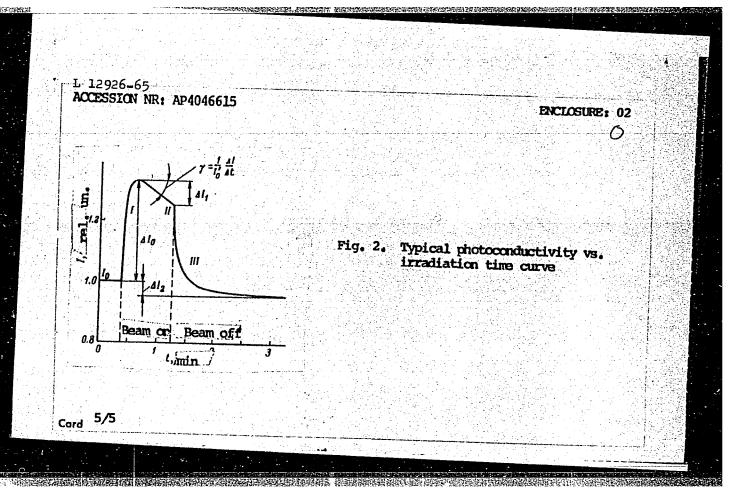
L 12926-65 ACCESSION NR: AP4046615

plates measuring 7 x 4 x 0.3--0.5 mm and having a surface resistivity 30--40 ohm cm. The measurements were carried out in vacuum at ~5 x 10⁻⁶ mm Hg. The current density employed in the measurements was usually 10^{-8} - 10^{-6} A/cm². The surface state was monitored by measuring the stationary photoconductivity of the samples. The schematic diagram of the measuring setup was shown in Fig. 1 of the enclosure, and a typical variation of the photoconductivity during the time of bombardment is shown in Fig. 2 of the enclosure. The results indicate that the processes occurring on the germanium surface can be of two kinds: redistribution of the charge in the surface layer, and outgassing under the influence of the electron beam. The rate of outgassing depends on the electron energy and exhibits a sharp maximum near 12--16 keV. Further study of the surface processes is planned, using combined measurements of the photoconductivity and of the field effect, as well as measurement of infrared photoconductivity during the electron bombardment. "The authors thank corresponding member AN SSSR, A. V. Rzhanov for continuous

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L 12926-65 ACCESSION NR: AP4046615	
interest in the work and for valuable remarks." O	Orig. art 1-
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sics and Semiconductor Electronics SO AN SSSR) SUBMITTED: 20Apr64	Solid State Phy-
SUB CODE: SS NR REF SOV: 003	ENCL: 02
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AT6033191

SOUNCE CODE: UR/3100/65/000/393/0001/0015

AUTHOR: Alikhanov, R. A.; Smirnov, L. S.

44 31

ORG: none

TITLE: Neutronographic investigation of the low-temperature magnetic transition

in chromium

SOURCE: USSR. Gosudarstvennyy komitet po ispol'zovaniyu atomnoy energii. Institut teoreticheskoy eksperimental'noy fiziki. Doklady, no. 393, 1965. Netronograficheskiye issledovaniya nizkotemperaturnogo magnitnogo prevrashcheniya v khrome. 1-15

TOPIC TAGS: chromium, cryostat, magnetic transition, low temperature magnetic transition, crystal spin structure, chromium crystal, neutron scattering, magnetic scattering

ABSTRACT: A neutronographic study was made of the low-temperature magnetic transition in samples of crystalline chromium and polycrystalline chromium containing equal answers of imparities but subjected to different thermomechanical treatment. A maniature crystat (weight 550 g, height 200 mm) was used. The

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study showed that t	he transition temperatu	re T _m increases	with an increa	ise in erature
metal plasticity, and	nd that the spin density niversal property of ch	modulation per loc romium. The au	thors thank P.	L.
Kanitsa for his inte	erest in this work and I.	. O. Panasyuka, I	J. D. Abanin,	1. 1.
Kostin, and T. I. I	<u>Kozlov</u> for their assista	nce. Orig. art. h	nas: 5 figures.	
[Authors' abstract]				
SUB CODE: 20/ S	UBM DATE: none/ Ol	RIG REF: 009/ O	TH REF: 009	1
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17556-66 EPF(n)-2/EWT(l)/EWT(m)/EWP(t) IJP(c) GG/AT/JD ACC NR: AP6006866 SOURCE CODE: UR/0181/66/008/002/0603/0603 В AUTHOR: Vasil'yev, A. V.; Smirnov. L. S. ORG: Institute of Semiconductor Physics, SO AN SSSR, Novosibirsk (Institut fiziki poluprovodníkov SO AN SSSR) TITLE: Infrared quenching of the natural photoconductivity in n-type germanium irradiated with gamma rays SOURCE: Fizika tverdogo tela, v. 8, no. 2, 1966, 603 TOPIC TAGS: gamma irradiation, photoconductivity, germanium semiconductor, germanium single crystal ABSTRACT: An investigation was made of the photoconductivity in n-type germanium 21, 44, 5 4 irradiated with gamma rays from a ${
m Co}^{60}$ source at room temperature. The specimens were cut from an ingot of n-type germanium with a donor concentration of $\sim 10^{14}$ cm⁻³. In a series of irradiated specimens the initial donors were almost totally compensated by acceptor centers introduced during irradiation. The following system of radiative defect levels in the forbidden zone was determined from the photoconductivity spectrum taken at the liquid nitrogen temperature: E_{C} =0.22, -0.25, -0.27, -0.30, -0.33, -0.36, -0.43, -0.49, -0.52, and -0.59 ev. The conductivity in its natural range was quite inertial. Its rise up to a stationary value took 12 sec its decrease took ~10 min. At constant illumination an infrared quenching throughout Card 1/2

L 17556-66

ACC NR: AP6006866

2

virtually the entire investigated range of wavelengths $(1.5-5.5~\mu)$ was observed in specimens compensated during irradiation. The quenching spectrum showed three clearly distinguished quenching maxima at 0.47, 0.52, and 0.60 ev. A weak quenching was also observed in the region of 0.2-0.4 ev. The results obtained apparently follow from a series of defects with different cross sections for electron and hole capture produced by irradiation. The quenching maxima at 0.47 and 0.52 ev can be attributed to the transfer of electrons initiated by infrared light from the valence zone to the E_{C} -0.27 and -0.22 ev levels, respectively. The maximum at 0.60 ev shows the presence of the E_{C} -0.14 ev level in the forbidden zone. Orig. art. has:

SUB CODE: 20/ SUBM DATE: 09Apr65/ OTH REF: 001/ ATD PRESS: 421/

Card 2/2 nst

SOURCE CODE: UR/0181/66/008/004/1246/1249 29959-66 EWT(1)/EYIT(m)/T/EWP(t)/ETI IJP(c) AT/JD Barinova, E. Yu.; Smirnov, ACC NR: AP6012492 AUTHORS: Geytsi, I. I.; Nesterov, A. A.; ORG: Institute of Semiconductors SO AN SSSR, Novosibirsk (Institut L. S. Temperature dependence of the average ionization energy in poluprovodníkov SO AN SSSR) Fizika tverdogo tela, v. 8, no. 4, 1966, 1246-1249 germanium and silicon TOPIC TAGS: germanium, silicon, ionization, temperature dependence, electron bombardment, x ray irradiation, photoelectric property, physical diffusion minority carrier forbidden hand seemes to be a seemed to be seemed to be a seemed to be a seemed to be a seemed to be a seem physical diffusion, minority carrier, forbidden band, serma NUML Semico NOUCTOR, SMICON SEMICONDUCTOR ABSTRACT: To obtain additional data on ionization occurring in semiconductors irradiated with electrons and x rays, the authors measured the temperature dependence of the average ionization in Ge and Si. The temperature dependence of the average ionization with temperature dependence of the average ionization and single the dependence of the average ionization with temperature was determined. the temperature dependence of the average lonization in we and St. The relative change of the ionization energy with temperature was determined by two procedures. X rays were used for uniform generation of carriers by two procedures. in the volume of the semiconductor and to avoid the influence of irradiation on its surface properties. The x rays range in energy from 30 to tion on its surface properties. The x rays range in 50 keV. The x ray pulses ranged in duration from 10 to 500 µsec, with

	L 46831-66 EWF(1)/EWT(m)/EWP(t)/ETI/T IJP(c) JD/AT ACC NR. AP6015464 (N) SOURCE CODE, UR (Alex for feet)	·*
	AUTHOR: Gerasimenko, N. N.: Loburets Yu. V. Delveler G. B. T.	7
	ORG: Institute of Semiconductor Physics, SO AN SSSR, Novosibirsk (Institut fiziki poluprovodnikov SO AN SSSR)	
	TITLE: Investigation of the recombination emission of cadmium sulfide subjected to electron	
	SOURCE: Fizika tverdogo tela, v. 8, no. 5, 1966, 1461-1466	+
	TOPIC TAGS: recombination emission, cadmium sulfide, electron excitation, semiconductor crystal, emission spectrum	
	ABSTRACT: The purpose of the present work is the investigation of the spectrum and the kinetics of recombination emission (RE) of unalloyed CdS single crystals subjected to excitation by a pulsed beam of high-energy (200-400kev) fast electrons. It is found that the green band the green band shifts toward the short wavelend.	
]	No substantial variations were observed in the intensity, the half-width, or the peak position of the red band of the RE spectrum after irradiation. These results preclude considering some	
	Card 1/2	

ACC NR: AP6037003 (A, N)

SOURCE CODE:

UR/0181/66/008/011/3403/3404

AUTHOR: Knaynovskaya, V. V.; Smirnov, L. S.

ORG: Institute of Physics of Semiconductors, SO AN SSSR, Novosibirsk (Institut fizi-

TITLE: Interaction between radiation defects and dislocations in germanium

SOURCE: Fizika tverdogo tela, v. 8, no. 11, 1966, 3403-3404

TOPIC TAGS: crystal defect, crystal dislocation phenomenon, germanium semiconductor, radiation effect, plastic deformation

ABSTRACT: To determine conditions for the recovery of the initial properties of germanium following irradiation, the authors observed the motion of dislocations during irradiation of germanium by a flux of 3.5-Mev electrons. p-type germanium with resistivity 5 ohm-cm and initial dislocation density 10^3 cm⁻² was subjected to plastic deformation in vacuum at 700C to introduce dislocations. To protect the introduced dislocations from impurities, the samples were coated with gold prior to deformation. The dislocation position was determined by an etching method. The tests showd that irradiation caused a definite motion of the etch pits relative to the initial position (in the [lll] direction), evidencing the climbing of the dislocations as they absorb vacancies or interstitial atoms. The average climbing distance was ~20 μ , corresponding to absorption of 10^{12} atoms per unit dislocation length. The dislocations were displaced by interaction with point defects only at

Card 1/2

GAVRICHKOV, Fedor Stepanovich; SHILIN, Boris Alekseyevich;
LYAKHOV, G.M., kand. tekhn. nauk, retsenzent; SMIRNOV,
L.V., otv. red.

克里特的时候 克斯 化双面流淌 医凹层点点形态 医结肠炎 化自己的对应的 医人名马克尔 医人名马克尔 医二氏征

[Miner of horizontal and inclined workings] Prokhodchik gorizontal'nykh i naklonnykh gornykh vyrabotok. Moskva, Nedra, 1965. 235 p. (MIRA 18:7)

SMIRNOV, L.V.; SABETSKIY, N.A.; MEZHERITSKAYA, N.P., tekhnicheskiy redaktor.

[Radio vision; aeronautical panoramic radar] Radiovidenie; samoletnyi panoramnyi radiolokator. Moskva, Voennoe izd-vo Ministerstva oborony Soiuza SSR, 1954, 56 p.

(Radar in aeronautics)

(Radar in aeronautics)

CIA-RDP86-00513R001651520016-4 "APPROVED FOR RELEASE: 08/25/2000

AID P - 4597

Subject

: USSR/Aeronautics - training

Card 1/1

Pub. 135 - 9/23

Author

Smirnov, L. V., Eng.-Lt. Col.

Title

Training of navigators in the ground trainer prior to

the bombing flight in overcast.

Periodical

: Vest. vozd. flota,38,3, 45-50, Mr 1956

Abstract

Detailed description of a simple bombing ground trainer for the training of navigators in bombing under adverse weather conditions. The aiming procedure is also described. One photo, 2 sketches. The article is of no

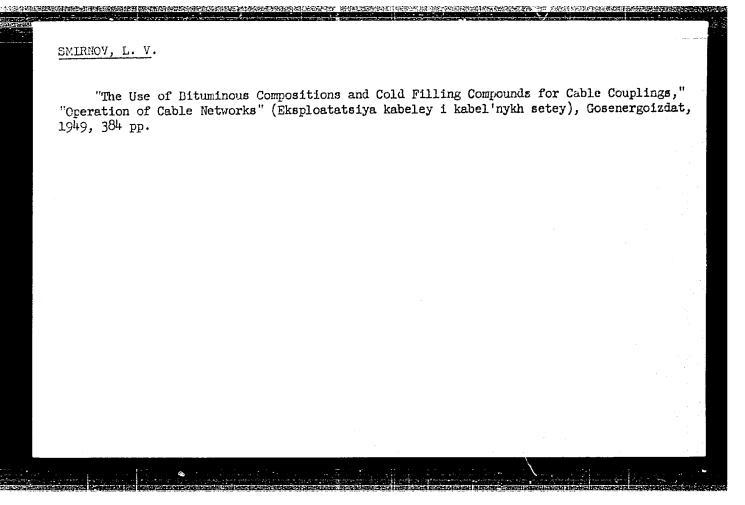
particular interest.

Institution: None

Submitted :

No date

APPROVED FOR RELEASE: 08/25/2000 CIA-RDP86-00513R001651520016-4"



SMIRNOV, L.V.; GORITSKIY, A.V., redaktor; SAVIN, M.M., redaktor; KOROVENKOVA, Z.A., tekhnicheskiy redaktor.

TARREST CONTROL OF THE PROPERTY AND THE PROPERTY OF THE PROPER

[Loading rock while driving vertical mine shafts] Pogruzka porody pri prokhodke vertikal nykh stvolov shakht. Moskva, Ugletekhizdat, 1955. 48 p. (MLRA 9:4) (Coal mines and mining)

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9 • !	Monthly	List of	Russian	Accessions,	Library o	f Congress,	August	•	Uncl.
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IVANOV, \$.Z.; SMIRNOV, L.V.

Characteristics of colorimetric glass from different sources. Sakh.prom. 27 no.8:31-33 Ag '53. (MLMA 6:8)

1. Leningradskiy tekhnologicheskiy institut pishchevoy promyshlennosti. (Glass) (Sugar--Analysis and testing)

APPROVED FOR RELEASE: 08/25/2000 CIA-RDP86-00513R001651520016-4"

IVANOV, S.Z.: SMIRNOV, L.V.; KAMINSKAYA, A.B.

Standardisation of the technical unit of chromaticity. Sakh.prom. 31 no.3:23-25 Mr *57. (MERA 10:4)

1. Leningradskiy tekhnologicheskiy institut pishchevoy promyshlennosti.

(Sugar--Analysis and testing) (Gelor measurement)

FILIPPOVA, Ye.S.; YASOV, V.G.; MUSIYENKO, I.A.; ARTSIMOVICH, G.V.; EPSHTEYN, Ye.F., prof., doktor tekhm. nauk; USENKO, A.P.; SIRIK, V.F.; SMIRNOV, L.V., otv. red.; KOSTON'YAN, A.Ya., red. izd-va; MAKSIMOVA, V.V., tekhn. red.

[Combination drilling of holes with hydraulic drills] Udarno-vrashchatel noe burenie skvazhin gidroudarnikami. Moskva, Gosgortekhizdat, 1963. 83 p. (Boring) (MIRA 16:5)

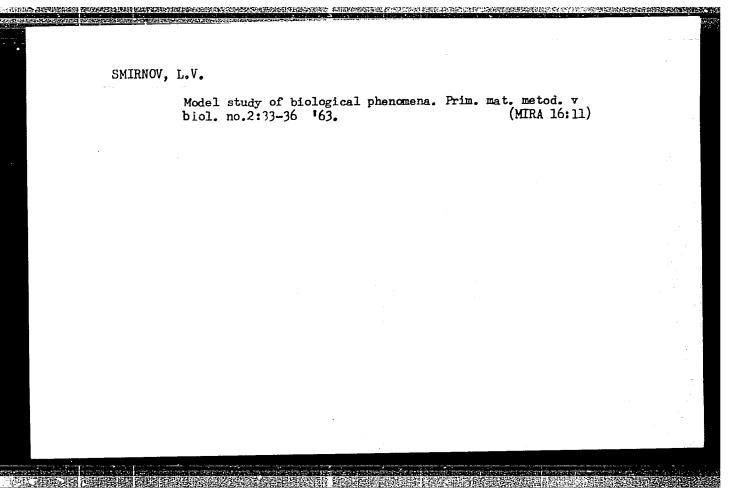
APPROVED FOR RELEASE: 08/25/2000 CIA-RDP86-00513R001651520016-4"

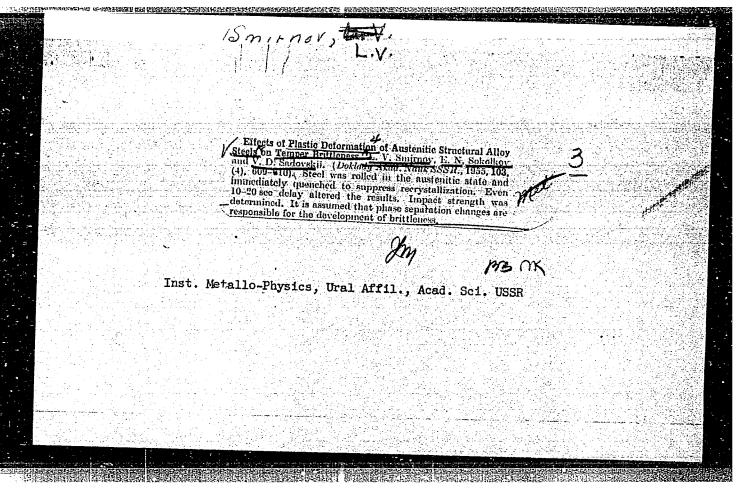
SMIRNOV, L.V. (Leningrad)

"The Simulation of Biological Phenomena"

Report presented at the 3rd Conference on the use of Mathemetics in Biology, Leningrad University, 23-28 Jan. 1961.

(Primeneniye matematicheskikh Metodov v Biologii. II, Leningrad, 1963 pp 5-11)





OMIRNOV, L.V

USSR/Solid State Physics - Mechanical Properties of Crystals and Polycrystalline Compounds.

E-10

Abs Jour

: Referat Zhur - Fizika, No 5, 1957, 11938

Author

Smirnov, L.V., Sadovskiy, V.D.

Inst Title

: Investigation of the Reversible Temper Brittleness of

Structural Alloyed Steels.

Orig Pub

: Probl. metalloved. i term. obrabotok, Moskova - Sverdlovsk,

Abstract

: A study was made of the influence of the effect of the following factors on the development of reversible temper brittleness: prolonged high temper, preliminary reheating, and plastic deformation in the austenitic state. An explanation is proposed fro the obtained results, and there practical significance is indicated, particularly with respect to possible methods for improving the structure of

overheated steel. Bibliography, 8 titles.

Card 1/1

SOV/137-57-10-20073

Translation from: Referativnyy zhurnal, Metallurgiya, 1957, Nr 10, p 233 (USSR)

AUTHORS. Smirnov, L.V., Sadovskiy, V.D.

TITLE: The Structural Mechanism of Tr

The Structural Mechanism of Transformations During the Heating of Steel (K voprosy o strukturnom mekhanizme prevrashcheniy pri nagreve stali)

PERIODICAL: Tr. In-ta fiz. metallov. Ural'skiy fil. AN SSSR, 1956, Nr 17, pp 94-110

ABSTRACT An examination is made of the structural mechanism of the formation of austenite in the heating of steel. The possibility of nondiffusive transformation of martensite into austenite with heating, by suppression of the diffusive processes of decomposition (through raising the rate of heating, or by alloying), in a fashion similar to the supercooling of austenite to the martensite point on cooling, is qualitatively proved. Gradient heating followed by structure study is used on specimens of 37KhNZA steel to investigate austenite formation. It is

Card 1/2 shown that austenite formation may proceed either by a diffusive

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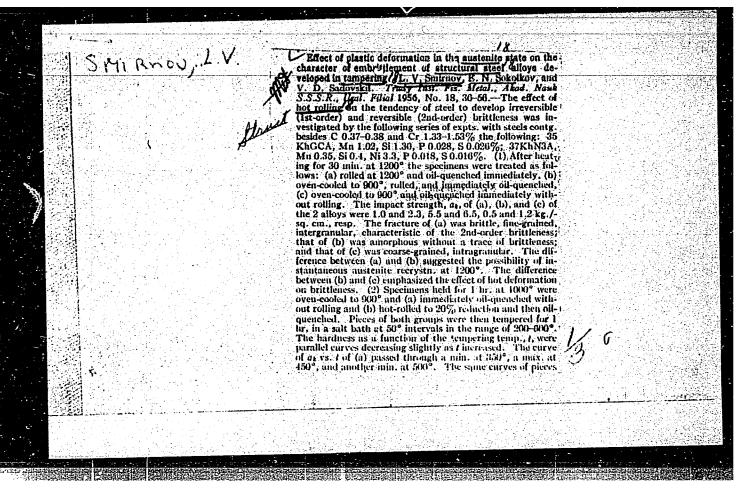
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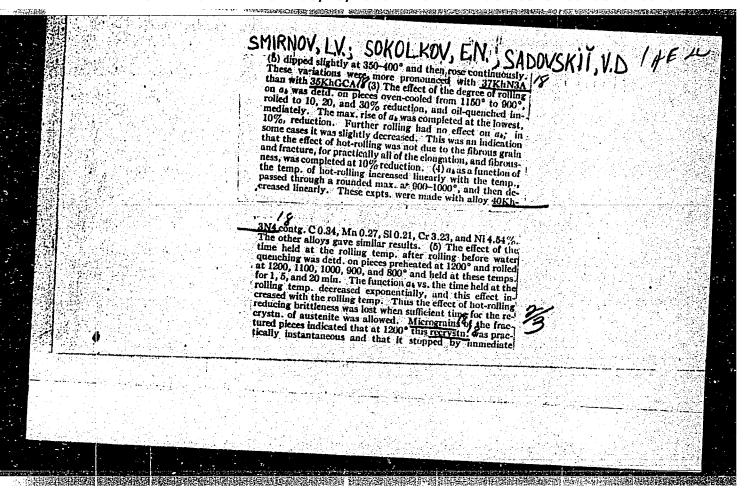
The Structural Mechanism of Transformations During the Heating of Steel

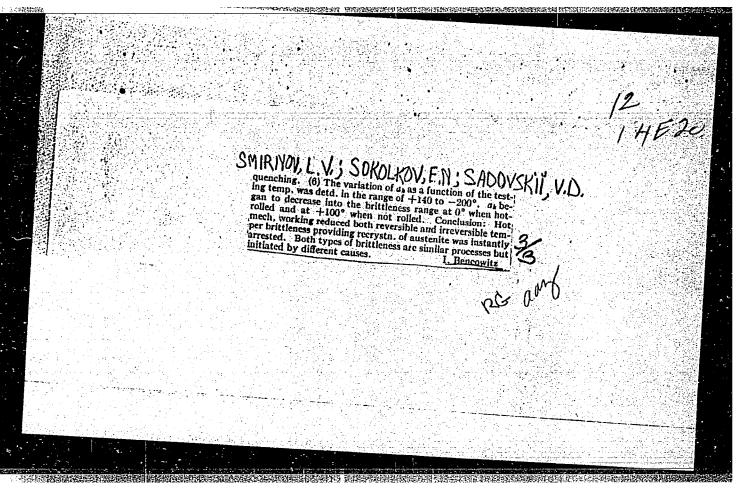
reaction of ferrite and carbides or by an intermediate process with partial precipitation of the C from the martensite, in which case the residual a solution of the alloying elements undergoes a "nondiffusive" ordering transformation, or by a truly nondiffusive reversible martensitic transformation. Various transformation mechanisms may come into play, depending upon the conditions of heating.

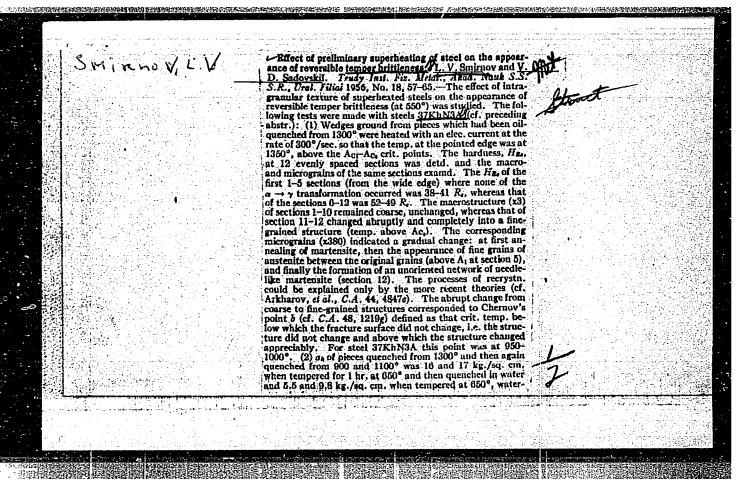
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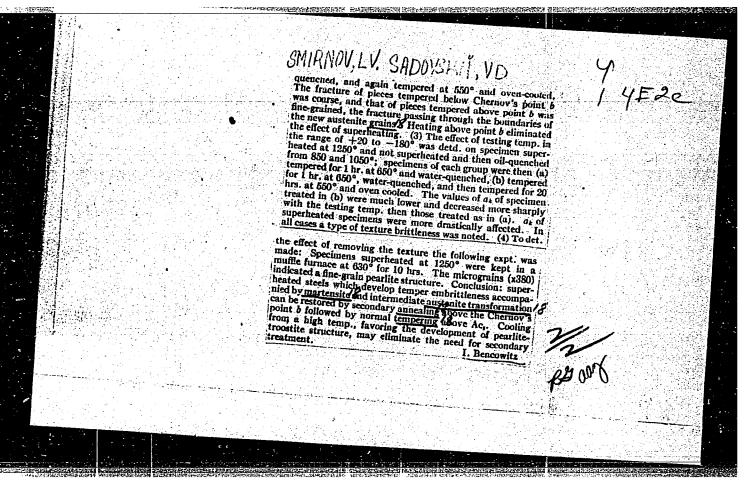
Card 2/2











SOV/124-58-11-13627

Translation from: Referativnyy zhurnal, Mekhanika, 1958, Nr 11, p 233 (USSR)

AUTHORS: Sadovskiy, V.D., Malyshev, K.A., Sokolkov, Ye. N., Smirnov, L.V.,

Bogacheva, G. N., Biryulin, V. T., Petrova, S. N.

TITLE: The Influence of High-temperature Plastic Deformation on the Temper

and Aging Brittleness of Quenched Steels (Vliyaniye plasticheskoy deformatsii pri vysokikh temperaturakh na khrupkost pri otpuske i

starenii zakalennykh staley)

PERIODICAL: V sb.: Issled. po zharoprochn. splavam. Vol 2. Moscow, AN SSSR,

1957, pp 76-91

ABSTRACT: As a result of tests it was found that the brittleness developed upon

aging of austenite steel of the 60Kh4G8N8V type, as well as upon aging of industrial high-temperature steel, can be held down through the application of a combined thermomechanical treatment consisting of the quench-hardening of a plastically deformed nonrecrystallized austenite. The authors explain the effect of the thermomechanical treatment by the sharp localization of the deformation, which at

elevated temperatures proceeds along the grain boundary, which leads

Card 1/2 to a reduction in the unfavorable effect of the phases that separate out

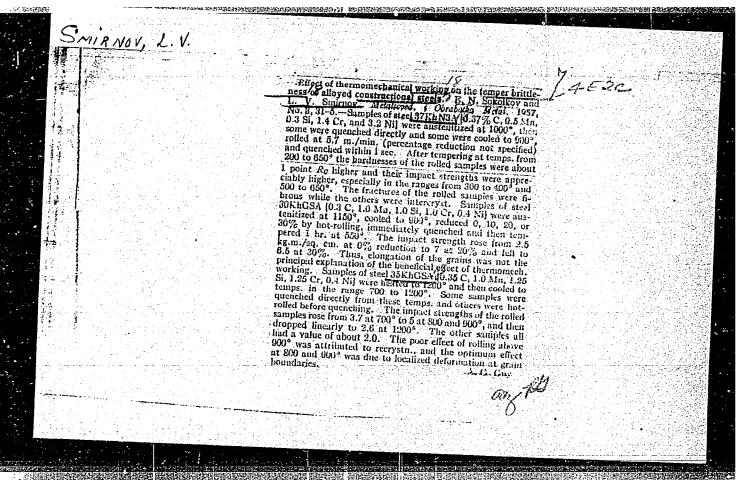
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The Influence of High-temperature Plastic Deformation (cont.)

along the boundaries during the tempering and contribute to the development of

D. M. Vasil'yev

Card 2/2



SOV/126-6-2-12/34 AUTHORS: Sokolkov, Ye. N., Smirnov, L. V. and Petrova, S. N.

Influence of Thermo-mechanical Treatment Under Conditions TITLE:

of Forging on the Impact Strength of Alloy Steels (Vliyaniye termomekhanicheskoy obrabotki v usloviyakh kovki na udarnuyu vyazkost' konstruktsionnykh

legirovannykh staley)

PERIODICAL: Fizika Metallov i Metallovedeniye, 1958, Vol 6, Nr 2, pp 276-280 (USSR)

ABSTRACT: In earlier work (Refs.1-3) it was established that combination of hot rolling of steel in the austenitic state with a hardening regime such as to eliminate recrystallisation of austenite enables to reduce the drop in impact strength

after tempering at temperatures at which temper brittleness develops. The authors considered it of interest to study the effect of such "thermo-mechanical" treatment under conditions of free forging. The experiments were effected on the commercial steels 37KhNZA and As blanks, beams of 20 x 20 x 200 mm were used; the forging was effected by means of a pneumatic hammer

with a reduction of 20%. Four differing regimes were Card 1/4 used, namely: heating to 1150°C, cooling down to 950°C,

Influence of Thermo-mechanical Treatment under Conditions of Forging on the Impact Strength of Alloy Steels

forging, quenching; heating to 1150°C, forging, quenching; heating to 1150°C, cooling to 950°C, forging, soaking in a furnace (1150°C for 5 minutes), quenching; heating to 1150°C, quenching. The cooling to 950°C was applied as a means of impeding possible recrystallisation during forging. For the same reason the time necessary for obtaining the desired reduction was reduced to the possible minimum and amounted to 4-5 secs which was followed immediately by quenching. After quenching, standard specimens of 10 x 10 x 60 mm were produced by grinding for impact bend tests. All the specimens were tempered at a temperature at which reversible temper brittleness occurs (550°C for four hours). On the finally machined specimens a notch 2 mm wide, 2 mm deep with a curvature radius of 1 mm at the bottom of the notch was produced. The obtained impact strength and hardness values are given in a table, p 276. Microstructure photographs and photographs of fractures are reproduced. It was found that "thermo-mechanical"

SOV/126-6-2-12/34 Influence of Thermo-mechanical Treatment Under Conditions of Forging on the Impact Strength of Alloy Steels

conditions of rolling brings about a reduction of the sensitivity of the steel to develop reversible temper brittleness. In both cases this effect is associated with the localisation of the deformation along the boundaries of the austenite grains of the initial heating, distortions in the crystal lattice of the intergranular transient zones (which are conserved after hardening) and the thereby caused change in the form of the phases and compounds which are responsible for developing temper brittleness. The here described effect of thermo-mechanical treatment can also be observed in other types of hot working as, for instance, stamping and extrusion, under conditions such that recrystallisation of workhardened austenite is prevented.

Card 3/4

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SOV/126-6-2-12/34

Influence of Thermo-mechanical Treatment Under Conditions of Forging on the Impact Strength of Alloy Steels

There are 3 figures, 1 table and 4 references, 3 of which are Soviet, 1 German.

ASSOCIATION: Institut fiziki metallov Ural'skogo filiala AN SSSR (Institute of Metal Physics, Ural Branch of the Ac.Sc. USSR)

SUBMITTED: November 19, 1956.

Card 4/4 1. Steel-Mechanical properties 2. Steel-Temperature factors

3. Steel--Test results

SADOVSKIY, V.D.; BOGACHEVA, G.N.; SMIHNOV, L.V.; SOROKIN, I.P.; KOMPANEYTSEV, N.A.

Investigating phase recrystallization in titanium. Fiz. met. i (MIRA 13:10)

metalloved. 10 no.3:397-403 S '60.

1. Institut fiziki metallov AN SSSR.

(Titanium-Metallography)

(Phase rule and equilibrium)

24,2200

26567

s/126/61/012/002/019/019

187500

also 1160 1482

E073/E535

AUTHORS:

Sadovskiy, V.D., Rodigin, N.M., Smirnov, L.V.,

Filonchik, G.M. and Fakidov, I.G.

TITLE:

On the influence of a magnetic field on the martensitic

transformations in steel

PERIODICAL: Fizika metallov i metallovedeniye, 1961, Vol.12, No.2,

pp.302-304

The authors investigated the effect of a magnetic field on martensitic transformations using specimens 3 mm dia., TEXT: 50 mm long, of steel QX2H (9Kh2N) (0.9% C, 1.83% Cr, 0.53% Ni, 0.27% Si, 0.30% Mn, 0.01% S, 0.018% P). These specimens were quenched from 850 and 1000°C in oil (so that they contained respectively 11 and 37% residual austenite) and were then subjected to a single magnetization by means of super-strong magnetic field pulses (200-350 kOe, 3000 c.p.s.). Magnetic measurements by a ballistic method did not show any increase in the martensite. Experiments at liquid nitrogen temperature also did not reveal a decrease [Abstractor's Note: Printing error for increase] in the quantity of residual austenite as a result of Card 1/4

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On the influence of a magnetic field ... 5/126/61/012/002/019/019

applying the magnetic field; only the usual increase in the quantity of martensite corresponding to deep cooling was observed. An increase in the number of magnetization cycles to five also had Thus, it can be concluded that in the general case pulse magnetization even with very strong fields does not produce transformation of residual austenite in quenched Further experiments were made with steel 50XHJ3 (50KhN23) (0.52% C, 1.49% Cr, 22.85% Ni, 0.3% Si, 0.19% Mn, 0.068% P). Quenching of this steel from 1200°C yields a purely austenitic structure at room temperature. Martensitic transformation begins at about -100°C and at liquid nitrogen temperature the residual austenite amounts to 40-50%. Fifty pulse magnetization cycles (40-50 k0e) during cooling showed only a very slight effect on the quantity of martensite. Further experiments were carried out on the assumption that the martensitic point is lower for fine grained austenite than for coarse grained. Therefore, another series of experiments was carried out in which steel 50KhN23 was water quenched from 1200°C and cold rolled with a reduction of 60% and then again water quenched from 850, 900, 950 and 1000°C; this Card 2/4

Card 3/4

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On the influence of a magnetic field ... S/126/61/012/002/019/019 E073/E535

material was used for producing magnetometric specimens. At room temperature all the specimens had a purely austenitic structure but their grain size differed. Cooling in liquid nitrogen revealed that specimens quenched from 850, 900 and 950°C contained 1 to 3% martensite but the coarser grain specimens, which were originally quenched from 1000°C, contained 20 to 30% martensite after cooling in liquid nitrogen. However, pulse magnetization at liquid nitrogen temperature produced intensive austenite to martensite transformation even in the fine grained specimens The increase in the number of magnetquenched from 850 to 900°C. ization cycles did not have a great influence. It is concluded that pulse magnetization can intensify austenite to martensite transformation. In the investigated case, the austenite was artificially stabilized by its fine grain size and is in a supermetastable state at the liquid nitrogen temperature, being undercooled considerably below its normal martensitic point. Activation of the transformation under the effect of a magnetic field is probably due to magnetostriction effects associated with the presence of a certain quantity of the magnetic phase. The problem

26567

On the influence of a magnetic field ... S/126/61/012/002/019/019

requires further study. There are 3 figures and 6 references: 4 Soviet and 1 English which reads as follows: Metal treatment and Drop Forging, 1960, 27, No.180, 362.

Institut fiziki metallov AN SSSR ASSOCIATION:

(Institute of Physics of Metals AS USSR)

May 22, 1961 SUBMITTED:

Card 4/4

SHAPIRO, N.I.; SMIRNOV, L.V.

Efficient method of preparing a solid metal open-hearth furnace charge. Stal' 21 no.9:850-852 S '61. (MIRA 1/:9)

1. Giprostal'. (Open-hearth furnaces.—Equipment and supplies) (Scrap metals)

44165 s/181/62/004/012/010/052 B104/B102

Bogoroditskiy, N. P., and Smirnov, L. V.

AUTHORS:

Problem of the anomalous polarization of titanium

TITLE:

dioxide (rutile)

Fizika tverdogo tela, v. 4, no. 12, 1962, 3418-3421

PERIODICAL:

TEXT: In studies of the anomalous polarization of rutile ceramics (G.I. Skanavi and A.I. Demeshina, ZhETF, XIX, 3, 949; Ya.M. Ksendzov, ZhTF, XX, 1, 117, 1950; L.I. Reymerov, ZhTF, XXVI, 3, 1960; Ya.M. Ksendzov, Tzv. AN SSSR, ser. fiz., 22, 3, 287, 1958) the ohmic conductivity was assumed to be low enough in comparison with the capacitive component for it to be heglected. Here the correctness of this assumption is checked. The electric properties (E, tano, $\varepsilon_{\rm eff}$) of identically prepared TiO₂ specimens containing Nb205 impurities, with Ag-Ag and Ag-In electrodes, as well as the volt-ampere characteristic of the Ag-TiO2 contacts were investigated. It became evident that the high-resistance contact layers must be considered. What are called the anomalous effects are attributed

Card 1/2

00086-00513R001651520016-4"

S/126/62/013/003/007/023 · E193/E383 The effect of of test pieces was subject to the same heating/cooling cycle without, however, plastic deformation at $800\,^\circ$ C. Creep tests were carried out at $500\,^\circ$ C on test pieces of each series. The :0 results are reproduced in Fig. 3, where the stress (o, kg/mm²) is plotted against time-to-rupture (τ_p , hrs), the continuous and broken curves relating, respectively, to 45 material subjected to TMO and to the pilot test pieces. The rate of steady creep amounting to 1.1 \times 10 $^{-1}$ %/hr for the pi 1 %/hr for the pilot test pieces was 3.5×10^{-4} %/hr for material subjected to TMO. Since it could be postulated that the higher creep resistance of specimens subjected to TMO was due to their higher hardness (100 BHN as compared with 60 BHN of nickel quenched from 800 °C), a supplementary series of tests was carried out on specimens given the following treatment: heating to 1 100 °C; quenching; . 25% reduction by rolling at 300 °C and 12 hours annealing at 500 °c. The results are reproduced in a table. It will be Card 2/4

ROMANOV, Ye.P.; SMIRNOV, L.V.; SADOVSKIY, V.D.; VOLKENSHTEYN, N.V.

Critical current of a disperse superconducting phase obtained during aging. Fiz. met. i metalloved. 20 nc.3:455-458 S 165. (MERA 18:11)

1. Institut fiziki metallov AN SSSR.

APPROVED FOR RELEASE: 08/25/2000 CIA-RDP86-00513R001651520016-4"

EMP(z)/EMP(c)/EMT(m)/EMP(b)/T/EMA(d)/EMP(t)MJW/JD UR/0126/65/019/004/0592/0595 ACCESSION NR: AP5011754 669.112.227.34:538.69. AUTHOR: Fokina, Ye. A.; Smirnov, L. V.; Sadovskiy, V. D. TITLE: Effect of a pulsed magnetic field on the temperature interval of martensitic transformation in steel SOURCE: Fizika metallov i metallovedeniye, v. 19, no. 4, 1965, 592-595 TOPIC TAGS: martensitic transformation, steel, magnetic treatmen ABSTRACT: Several grades of steel were studied in an attempt to determine the effect which an applied pulsed magnetic field has on the position of the martensitic transformation temperature range. The chemical compositions of the steels studied are given in table 1 of the Enclosure. The magnetometric method was used to determine the martensite points and the quantity of ferromagnetic phase. The amplitude of the field was 400,000 cersteds at a frequency of 5 kc. It was found that the temperature of martensitic transformation in steels and iron-base carbon-free alloys is shifted toward the higher temperature side under the action of a pulsed magnetic field. The amount of this shift at a given supercooling value increases with Card 1/3

62542-65 ACCESSION NR: AP5011754		3
the field strength as does the field causes additional dissoc small and can hardly have any gratitude to I. G. Fakindov an ments where superstrong pulsed figures, 2 tables.	practical significance. " d E. A. Zavadskiy for help magnetic fields were used	The authors express their in carrying out the experi-
ASSOCIATION: Institut fiziki AN SSSR)	metallov AN SSSR (Institut	e of Physics of Metals,
SUBMITTED: 16Jul64	ENCL: 01	SUB CODE: MM, EM
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ACCESSION NR:/ A	P5011754				EN	ICLOSURE:	01	9
			TABLE 1					
Grade of steel				Chemical	Composi	tion, %		
	С	Ni	Cr	Mn	Si	Мо	ν	
50Kh2N22	0.49	21.9	2.04	0.26	0.63			
OKhN23	0.52	22.8	1.49	0.19	0.30	-	-	
0Kh2N16 4	0.52	16.44	2.01	0.47	0.63	-	-	
OKh2N3	0.51	3.21	2.00	0.35	0.11	•	-	
25N24M2	0.21	24.10	-	0.22	0.06	2.16	∤	
130 18	0.06	29.72		0.15	- ·	•		
(h12F 8	1.35	-	12.3	0.19	•	-	0.92	
ShKh15	1.09	-	1.37	0.30	0.26		•	
<u>J12</u>	1.25	-	0.2	0.33	0.26	•		
	1							

EWT(d)/EWT(m)/EWP(w)/EWA(d)/T/EWP(t)/EWP(k)/EWP(z)/EWP(b)/EWA(d) Pf-4/Pad - IJP(c) MJW/JD/HW/JG/EM UR/0126/65/019/005/0722/0725 ACCESSION NR: AP5013810 669.112.227.34 : 538.69 60 54 AUTHOR: Fokina, Ye. A.; Smirnov, L. V.; Sadovskiy, V. D. B TITLE: Destabilization of austenite by a powerful pulsed magnetic field SOURCE: Fizika metallov i metallovedeniye, v. 19, no. 5, 1965, 722-725 TOPIC TAGS: destabilized austenite, stabilized austenite, martensite transformation, pulsed magnetic field, plastic deformation, supercooled austenite, kinetic maximum ABSTRACT: The authors investigated the effect of a pulsed magnetic field on: austenite stabilized by plastic deformation in 50Kh2N22 steel (0,49% C, 21.9% N1; 2.04% Cr, 0.26% Mn, 0.63% Si); austenite stabilized by isothermal exposure to temperatures above the martensite point in N14Kh10 steel (0.05% C, 13.73% Ni, 9.70% Cr, 0.33% Mn, 0.48% Si); martensite transformation in austenite supercooled to the temperature range below the kinetic maximum in N24G4 steel (0.03% C, 23.6% Ni, 3.6% Mn) (0 to -196°C). The amount of martensite in the specimens was controlled by the magnetometric method. Card

The pulsed refer generation Zavadski mplitude in ately 5000 magnetic fidegree of mof the field to an increfield desta alloys with range below pulsed magnetransformat	lng superpowerful ply (Fizika metallove the experiments reps. It was establed in all cases leartensite transformed applied. The incase in the magnitude bilizes sustenite isothermal martens the kinetic maximulation also being a first consider it their	i metailovedeni eached 500 k-oer lished that the ads to the destantion being them rease in the degle of the threshold the transformation (to the temper a martensite transformation of the ir pleasant duty	accomplished in an itelds, described by ye, 1958, 6, 569). steds and the frequestion of the bilization of auster a function of the ree of plastic deford field. The pulsiter's thermal stabilon, supercooled to ature of liquid nite ansformation, the destruction of the field express their application of the field assistance in conception fields, and	The field ency, approxi- pulsed nite, the intensity rmation leads ed magnetic lization. In a temperature rogen) the egree of this d applied. preciation to lucting the
experiments dina and E	employing superpo	werful pulsed ma eir kindness in p	gnetic fields, and royiding alloy spec	imens."
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ACCESSION NR: AP5013810		
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Orig. art. has: 4 lightes, ASSOCIATION: Institut fizik	i metallov AN SSSR (Instit	nite or netal injury
AN SSSR) SUBMITTED: 28Ju164	ENGL: 00	SUB CODE: MM, EM
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L 4186-66 EWT(m)/EPF(c)/EWA(d)/T/EWP(t)/EWP(z)/EWP(b)/EWA(c) ACCESSION NR: AP5016535 MJW/JD UR/0126/65/019/006/0932/0933 AUTHOR: Fokina, Ye. A.; Smirnov, L. V.; Sadovskiy, V. D.; Prekul, A. F. TITLE: On the problem of the effect of a constant magnetic field on the martensite transformation in steel 14.44.55 SOURCE: Fizika metallov i metallovedeniye, v. 19, no. 6, 1965, 932-933 TOPIC TAGS: martensitic transformation, constant magnetic field, strong magnetic field, liquid helium, steel ABSTRACT: At the Institute of Physics of Metals experiments were performed on 50KhN23 steel in a slowly increasing then constant (for 6 min) magnetic field of 40 kOe in a solenoid with a superconducting winding at liquid helium temperature. Without the magnetic field, this steel does not undergo a martensite transformation on cooling to -196°C, but cooling to the liquid helium temperature causes the formation of 8-9% martensite. When the field was applied, an additional 12% martensite was formed. Similar experiments with the same steel carried out at the Physics Institute gave analogous results. In another steel, 50Kh2N22, in which no martensite is formed on cooling in liquid helium, the application of a constant magnetic Card 1/2

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tributed to the	influence of the med e field used was conse	ion of 8% martensite. martensite transformat chanical forces arising tant, not pulsed. "The affording them the opposite the composite the comp	It is concluded that to ion should not be at- during pulsed magnetic authors thank N. V. crtunity to carry out to	za-
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L 26646-66 EWT(m)/EPF(n)-2/T/EWP(t) IJP(c) JD/WW/JG ACC NR: AP5025333 SOURCE CODE: UR/0126/65/020/003/0455/0458 AUTHOR: Romanov, Ye. P.; Smirnov, L. V.; Sadovskiy, V. D.; Volkenshteyn, N. V. ORG: Institute of Metal Physics, AN SSSR (Institut fiziki metallov AN SSSR) TITLE: Critical current of the superconductive dispersion phase obtained during aging Fizika metallov i metallovedeniye, v. 20, no. 3, 1965, 455-458 SOURCE: TOPIC TAGS: martensitic transformation, zirconium base alloy, niobium containing alloy, superconductivity, metal aging, solid solution, plastic deformation, metal heat treatment, current density ABSTRACT: A nonsuperconductive alloy at 4.20K was used which could separate a superconductive dispersion phase during the process of thermal treatment or aging. The alloy used was zirconium with 4% niobium. After preparation, superconductivity was obtained even after short thermal treatment at a temperature of 500°Co. Maximum critical density is obtained after heating the sample for 21 hours. Further heating results in a decrease of critical current density. When heating the zirconium-4% niobium alloy a supersaturated niobium A-solid solution is obtained from the stable S-solid solution as a result of martensite transformation. Card 1/2

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L 26646-66				
ACC NR: AP5025333			4 14 2	0
Plastic deformation increace correspondingly increases because of the above phenowith increase of the degreativity in the alloy is export the matrix properties.	the density of separ omena, increase of cr ee of cold deformatio plained only by the s It can be noted tha	rations. It can be ritical current do on. The appearance separated phase wi at even a slight p	e assumed that ensity is observ ce of supercondu nich is independ phase separation	ed c- ent will
result in a considerable	increase of current d	lensity. Orig. a	rt. has: 5 fig.	
1.1, 6.0				
SUB CODE: 11,20 UBM DATE	: 19Mar65/ ORIG REF	?: 004/ OTH REF	: 008	
SUB CODE: 11,20 SUBM DATE	: 19Mar65/ ORIG REF	?: 004/ OTH REF	: 008	
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L 18730-66 EWT(1)/EWT(m)/EWA(d)/EWP(t) ACC NR: AP6005132 IJP(c) JD/GG SOURCE CODE: UR/0126/66/021/001/0017/0020 AUTHOR: Romanov, Ye. P.; Sadovskiy, V. D.; Volkenshteyn, N. V.; Smirnov, L. V. ORG: Institute of the Physics of Metals, AN SSSR (Institut fiziki metallov) TITLE: Disruption of superconductivity in an alloy with a disperse superconducting 21, 44, 15 ,--SOURCE: Fizika metallov i metallovedeniye, v. 21, no. 1, 1966, 17-20 70 TOPIC TAGS: superconductivity, zirconium alloy, magnetic field, solenoid B ABSTRACT: This is a continuation of a previous investigation (Romanov et al. FMM, 1965, 20, 3) with the difference that it presents certain findings on the disruption of superconductivity in the alloy of Zr with 4% Nb by weight following the decomposimeans of a superconducting solenoid at 4.2°K. The current was introduced at a smoothly increasing rate into the specimens by means of a semiconductor amplifier and the disruption of superconductivity was recorded by means of an automatic-recording millivolt meter. It is found that for the alloy investigated the transition from superconducting to normal state is abrupt in the absence of the magnetic field and increasingly smooth the greater is the intensity of the magnetic field applied. Plotting of the curves of electric resistance as a function of the current introduced (Fig. 1) revealed that Card 1/3 UDC: 539.292:537.312.62